

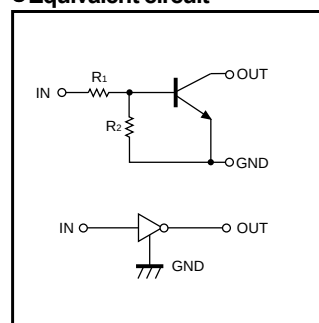
Digital transistors (built-in resistors)

**DTC143XM / DTC143XE / DTC143XUA /
DTC143XKA / DTC143XSA**

● Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see the equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making device design easy.

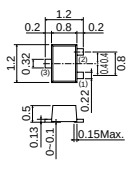
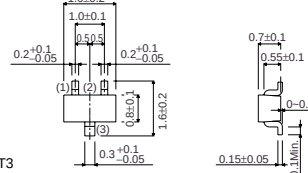
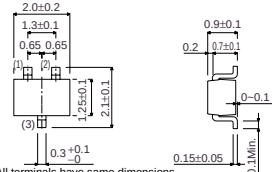
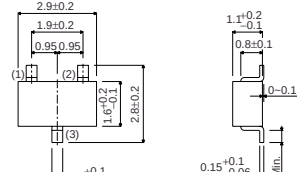
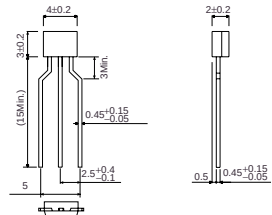
●Equivalent circuit



● Structure

NPN digital transistor (with built-in resistors)

●External dimensions (Units : mm)

DTC143XM  ROHM : VMT3 Abbreviated symbol : 43 (1) IN (2) GND (3) OUT	DTC143XE  ROHM : EMT3 Abbreviated symbol : 43 (1) GND (2) IN (3) OUT
DTC143XUA  ROHM : UMT3 EIAJ : SC-70 All terminals have same dimensions Abbreviated symbol : 43 (1) GND (2) IN (3) OUT	DTC143XKA  ROHM : SMT3 EIAJ : SC-59 All terminals have same dimensions Abbreviated symbol : 43 (1) GND (2) IN (3) OUT
DTC143XSA  ROHM : SPT EIAJ : SC-72 Abbreviated symbol : 43 (1) GND (2) OUT (3) IN	

DTC143XM / DTC143XE / DTC143XUA DTC143XKA / DTC143XSA

Transistors

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits(DTC143X□)					Unit
		M	E	UA	KA	SA	
Supply voltage	V _{CC}	50					V
Input voltage	V _{IN}	-7~+20					V
Output current	I _O	100					mA
	I _{C(Max.)}	100					
Power dissipation	P _d	150		200		300	mW
Junction temperature	T _j	150					°C
Storage temperature	T _{stg}	-55~+150					°C

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V _{I(off)}	—	—	0.3	V	V _{CC} =5V, I _O =100μA
	V _{I(on)}	2.5	—	—		V _O =0.3V, I _O =20mA
Output voltage	V _{O(on)}	—	0.1	0.3	V	I _O /I _I =10mA/0.5mA
Input current	I _I	—	—	1.8	mA	V _I =5V
Output current	I _{O(off)}	—	—	0.5	μA	V _{CC} =50V, V _I =0V
DC current gain	G _I	30	—	—	—	V _O =5V, I _O =10mA
Input resistance	R ₁	3.29	4.7	6.11	kΩ	—
Resistance ratio	R ₂ /R ₁	1.7	2.1	2.6	—	—
Transition frequency	f _T	—	250	—	MHz	V _{CE} =10V, I _E =-5mA, f=100MHz *

* Transition frequency of the device

●Packaging specifications

Type	Package	VMT3	EMT3	UMT3	SMT3	SPT
	Packaging type	Taping	Taping	Taping	Taping	Taping
	Code	T2L	TL	T106	T146	TP
	Basic ordering unit (pieces)	8000	3000	3000	3000	5000
DTC143XM		○	—	—	—	—
DTC143XE		—	○	—	—	—
DTC143XUA		—	—	○	—	—
DTC143XKA		—	—	—	○	—
DTC143XSA		—	—	—	—	○

DTC143XM / DTC143XE / DTC143XUA DTC143XKA / DTC143XSA

Transistors

●Electrical characteristic curves

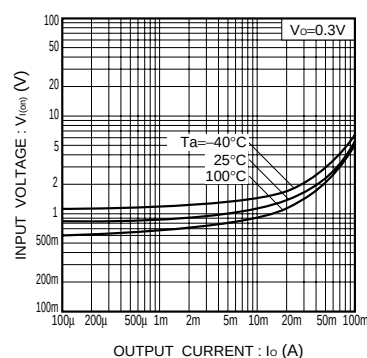


Fig.1 Input voltage vs. output current
(ON characteristics)

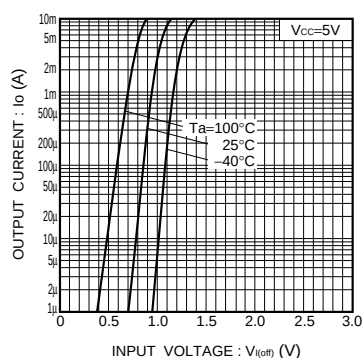


Fig.2 Output current vs. input voltage
(OFF characteristics)

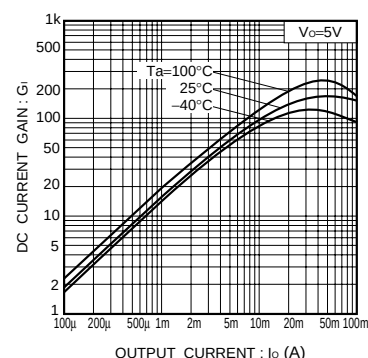


Fig.3 DC current gain vs. output
current

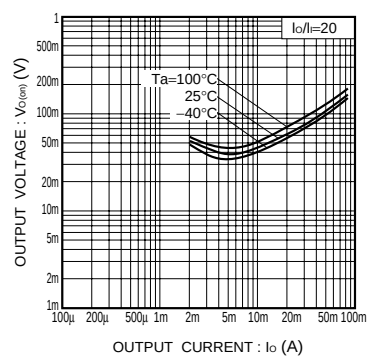


Fig.4 Output voltage vs. output
current